INTEGRATED CIRCUITS

DATA SHEET

74F125, **74F126**Quad buffers (3-State)

Product specification IC15 Data Handbook

1989 March 28





74F125, 74F126

FEATURE

 High impedance NPN base inputs for reduced loading (20μA in High and Low states)

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F125	5.0ns	23mA
74F126	5.0ns	26mA

ORDERING INFORMATION

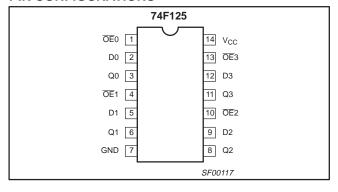
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V $\pm 10\%$, T_{amb} = 0°C to +70°C	PKG DWG #		
14-pin plastic DIP	N74F125N, N74F126N	SOT27-1		
14-pin plastic SO	N74F125D, N74F126D	SOT108-1		

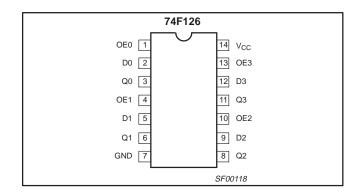
INPUT AND OUTPUT LOADING AND FAN OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
D0-D3	Data inputs	1.0/0.033	20μΑ/20μΑ
OE0-OE3	Output Enable inputs (active Low), 74F125	1.0/0.033	20μΑ/20μΑ
OE0-OE3	Output Enable inputs (active High), 74F126	1.0/0.033	20μΑ/20μΑ
Q0-Q3	Data outputs	750/106.7	15mA/64mA

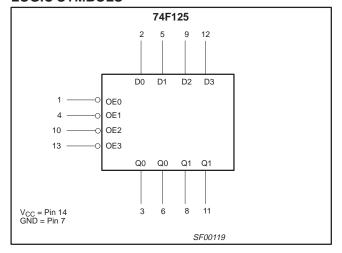
NOTE: One (1.0) FAST unit load is defined as: 20μA in the High state and 0.6mA in the Low state.

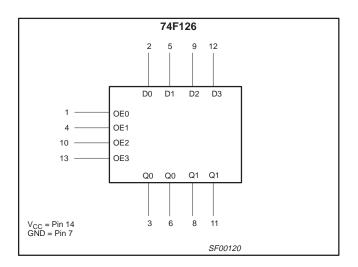
PIN CONFIGURATIONS





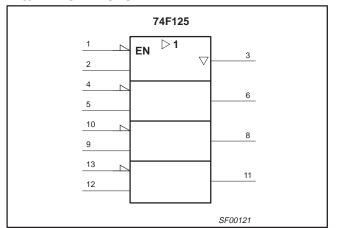
LOGIC SYMBOLS

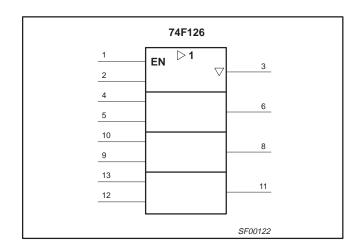




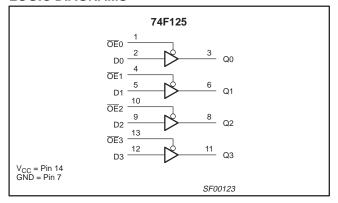
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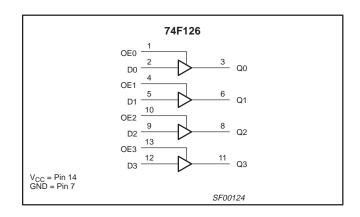
IEC/IEEE SYMBOLS





LOGIC DIAGRAMS





FUNCTION TABLE, 74F125

I NP	OUTPUT	
OE n	Dn	Qn
L	L	L
L	Н	Н
Н	X	Z

FUNCTION TABLE, 74F126

I NP	OUTPUT					
OEn	OEn Dn					
Н	L	L				
Н	Н	Н				
L	X	Z				

NOTES TO THE FUNCTION TABLES:

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	-0.5 to +7.0	V
V _{IN}	Input voltage	-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	–0.5 to V _{CC}	V
I _{OUT}	Current applied to output in Low output state	128	mA
T _{amb}	Operating free-air temperature range	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150	°C

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		UNIT		
STWIBOL	PARAMETER	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5.0	5.5	V
V _{IH}	High-level input voltage	2.0			V
V _{IL}	Low-level input voltage			0.8	V
I _{IK}	Input clamp current			-18	mA
I _{OH}	High-level output current			-15	mA
I _{OL}	Low-level output current			64	mA
T _{amb}	Operating free air temperature range	0		+70	°C

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

OVARDOL	DADAMETER				TEST CONDITIONS ¹					UNIT
SYMBOL	PARAMET	ER		l les	MIN	TYP ²	MAX	UNII		
						2.4			V	
V	Liab laval autout valta sa			$V_{CC} = MIN,$ $V_{IL} = MAX,$	I _{OH} =-3mA	±5%V _{CC}	2.7	3.3		V
V _{OH}	High-level output voltage	;		$V_{IH} = MIN$	1 15mA	±10%V _{CC}	2.0			V
					I _{OH} =–15mA	±5%V _{CC}	2.0			V
.,				$V_{CC} = MIN,$		±10%V _{CC}			0.55	V
V _{OL}	Low-level output voltage			$V_{IL} = MAX,$ $V_{IH} = MIN$	I _{OH} = MAX	±5%V _{CC}		0.42	0.55	V
V _{IK}	Input clamp voltage		V _{CC} = MIN, I _I =	I _{IK}			-0.73	-1.2	V	
I _I	Input current at maximum input voltage			V _{CC} = 0.0V, V _I = 7.0V					100	μΑ
I _{IH}	High-level input current			$V_{CC} = MAX, V_I = 2.7V$					20	μΑ
I _{IL}	Low-level input current			$V_{CC} = MAX, V_I = 0.5V$					-20	μΑ
I _{OZH}	Off-state output current, High-level voltage applie	d		$V_{CC} = MAX, V_O = 2.7V$					50	μΑ
I _{OZL}	Off-state output current, Low-level voltage applied	d		$V_{CC} = MAX, V_O = 0.5V$					-50	μΑ
Ios	Short circuit output curre	nt ³		V _{CC} = MAX			-100		-225	mA
			I _{CCH}		\overline{OE} n = GND,	Dn = 4.5V		17	24	mA
		74F125	I _{CCL}	$V_{CC} = MAX$	OEn = Dn = G	SND		28	40	mA
	Cumply ourrent (total)		I _{CCZ}	1	OE n = Dn = 4.5V			25	35	mA
Icc	Supply current (total)	I –	I _{CCH}	V _{CC} = MAX	OEn = Dn = 4.5V			20	30	mA
			I _{CCL}		OEn = 4.5V, Dn = GND			32	48	mA
	I _{CCZ}			OEn = GND, Dn = 4.5V				26	39	mA

NOTES:

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^{1.} For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

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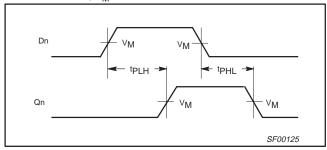
AC ELECTRICAL CHARACTERISTICS

SYMBOL PARAMET		TEST CONDITION		V_{CC} = +5.0V T_{amb} = +25°C C_L = 50pF, R_L = 500 Ω			V _{CC} = +5. T _{amb} = 0°0 C _L = 50pF,	UNIT	
				MIN	TYP	MAX	MIN	MAX]
t _{PLH} t _{PHL}	Propagation delay Dn to Qn		Waveform 1	2.0 3.0	4.0 5.5	6.0 7.5	2.0 3.0	6.5 8.0	ns
t _{PZH}	Output Enable time to High or Low level	74F125	Waveform 2 Waveform 3	3.5 4.0	5.5 6.0	7.5 8.0	3.5 4.0	8.5 9.0	ns
t _{PHZ}	Output Disable time from High or Low level		Waveform 2 Waveform 3	1.5 1.5	3.5 3.5	5.0 5.5	1.5 1.5	6.0 6.0	ns
t _{PLH} t _{PHL}	Propagation delay Dn to Qn		Waveform 1	2.0 3.0	4.0 5.5	6.5 8.0	2.0 3.0	7.0 8.5	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level	74F126	Waveform 2 Waveform 3	4.0 4.0	6.0 6.0	7.5 8.0	3.5 3.5	8.5 8.5	ns
t _{PHZ}	Output Disable time from High or Low level		Waveform 2 Waveform 3	2.0 3.0	4.5 5.5	6.5 7.5	2.0 3.0	7.5 8.0	ns

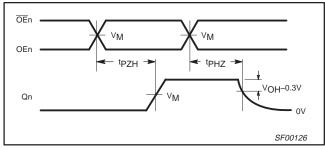
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AC WAVEFORMS

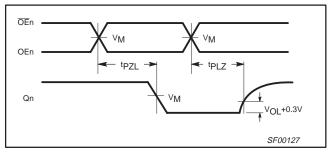
For all waveforms, $V_M = 1.5V$.



Waveform 1. Propagation Delay for Input to Output



Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level



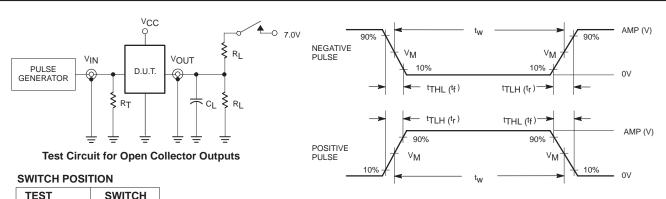
Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

Philips Semiconductors Product specification

Quad buffers (3-State)

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TEST CIRCUIT AND WAVEFORM



SWITCH
closed
closed
open

DEFINITIONS:

 R_L = Load resistor;

see AC electrical characteristics for value.
Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

Termination resistance should be equal to $Z_{\mbox{\scriptsize OUT}}$ of $R_T =$ pulse generators.

family	INP	INPUT PULSE REQUIREMENTS										
	amplitude	V_{M}	rep. rate	t _w	t _{TLH}	t _{THL}						
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns						

Input Pulse Definition

SF00128

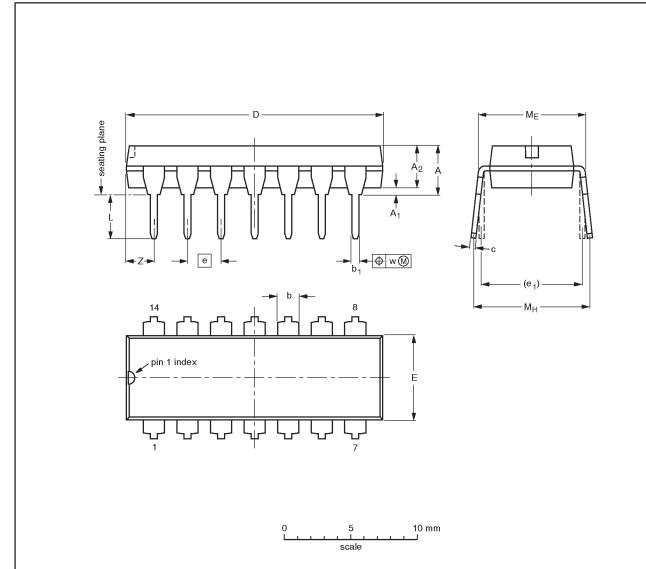
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Quad buffers (3-State)

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

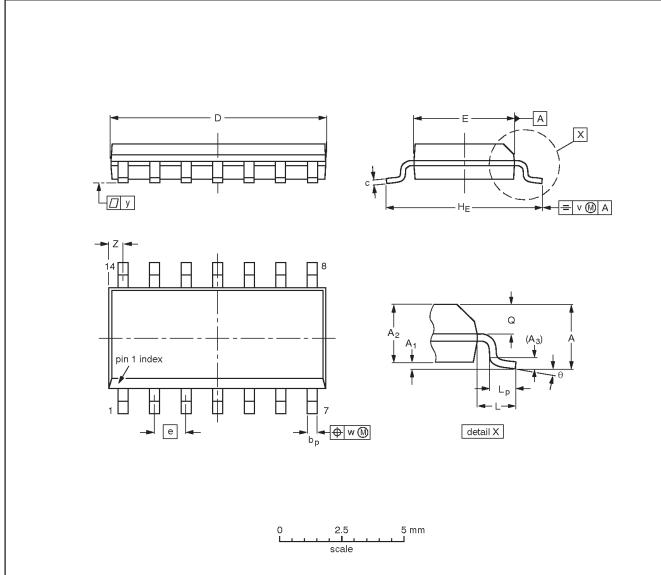
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001AA			92-11-17 95-03-11	

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	У	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06S	MS-012AB				-95-01-23- 97-05-22	

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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